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October 1997 Revised June 2005

74VCX16373

Low Voltage 16-Bit Transparent Latch with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear to be transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable (\overline{OE}) is LOW. When \overline{OE} is HIGH, the outputs are in a high impedance state.

The 74VCX16373 is designed for low voltage (1.2V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.2V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- \blacksquare t_{PD} (I_n to O_n)

3.0 ns max for 3.0V to 3.6V V_{CC}

- Power-off high impedance inputs and outputs
- Support live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL}) ±24 mA @ 3.0V V_{CC}
- Uses proprietary noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:

Human body model > 2000V

Machine model > 200V

■ Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA) (Preliminary)

Note 1: To ensure the high-impedance state during power up or power down, $\overline{\text{DE}}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

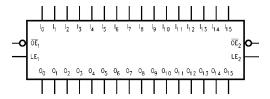
Ordering Code:

| Order Number | Package Number | Package Description |
|---------------------------------|-------------------------|-----------------------------------------------------------------------------|
| 74VCX16373G (Note 2)(Note 3) | BGA54A (Preliminary) | 54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide |
| 74VCX16373MTD (Note 3) | MTD48 | 48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide |

Note 2: Ordering Code "G" indicates Trays.

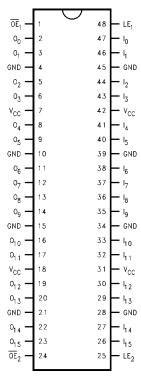
Note 3: Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

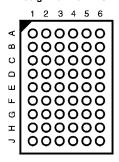


Connection Diagrams

Pin Assignment for TSSOP



Pin Assignment for FBGA



(Top Thru View)

Pin Descriptions

| Pin Names | Description |
|---------------------------------|----------------------------------|
| ŌĒn | Output Enable Input (Active LOW) |
| LE _n | Latch Enable Input |
| I ₀ -I ₁₅ | Inputs |
| O ₀ -O ₁₅ | Outputs |
| NC | No Connect |

FBGA Pin Assignments

| | 1 | 2 | 3 | 4 | 5 | 6 |
|---|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|
| Α | O ₀ | NC | OE ₁ | LE ₁ | NC | I ₀ |
| В | 02 | O ₁ | NC | NC | I ₁ | l ₂ |
| С | O ₄ | O ₃ | V _{CC} | V _{CC} | l ₃ | I ₄ |
| D | O ₆ | O ₅ | GND | GND | I ₅ | I ₆ |
| Е | O ₈ | O ₇ | GND | GND | I ₇ | I ₈ |
| F | O ₁₀ | O ₉ | GND | GND | l ₉ | I ₁₀ |
| G | O ₁₂ | O ₁₁ | V _{CC} | V _{CC} | I ₁₁ | I ₁₂ |
| Н | O ₁₄ | O ₁₃ | NC | NC | I ₁₃ | I ₁₄ |
| J | O ₁₅ | NC | OE ₂ | LE ₂ | NC | I ₁₅ |

Truth Tables

| | Inputs | | Outputs |
|-----------------|-----------------|--------------------------------|--------------------------------|
| LE ₁ | OE ₁ | I ₀ –I ₇ | 0 ₀ –0 ₇ |
| Х | Н | Х | Z |
| Н | L | L | L |
| Н | L | Н | Н |
| L | L | Χ | O_0 |

| | Inputs | | Outputs |
|-----------------|-----------------|---------------------------------|---------------------------------|
| LE ₂ | OE ₂ | I ₈ –I ₁₅ | O ₈ -O ₁₅ |
| Х | Н | Х | Z |
| Н | L | L | L |
| Н | L | Н | Н |
| L | L | Χ | O ₀ |

H = HIGH Voltage Level

L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

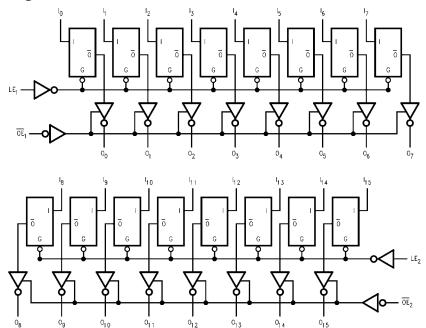
O₀ = Previous O₀ before HIGH-to-LOW of Latch Enable

Functional Description

The 74VCX16373 contains sixteen edge D-type latches with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the $\rm I_n$ enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time

its I input changes. When LE_n is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition on LE_n . The 3-STATE outputs are controlled by the Output Enable (\overline{OE}_n) input. When \overline{OE}_n is LOW the standard outputs are in the 2-state mode. When \overline{OE}_n is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 4)

Supply Voltage (V_{CC}) -0.5V to +4.6V DC Input Voltage (V_I) -0.5V to +4.6V Output Voltage (V_O)

Outputs 3-STATED -0.5V to +4.6V

Outputs Active (Note 5) -0.5V to V_{CC} +0.5V DC Input Diode Current (I_{IK}) $V_I < 0V$ -50 mA

DC Output Diode Current (I_{OK})

 $V_{O} < 0V$ -50 mA $V_O > V_{CC}$ +50 mA

DC Output Source/Sink Current

 (I_{OH}/I_{OL}) $\pm 50 \text{ mA}$

DC V_{CC} or GND Current per

±100 mA Supply Pin (I_{CC} or GND) -65°C to +150°C

Storage Temperature Range (T_{STG})

Recommended Operating Conditions (Note 6)

Power Supply

1.2V to 3.6V Operating Input Voltage -0.3V to +3.6V

Output Voltage (V_O)

Output in Active States 0.0V to V_{CC} Output in "OFF" State 0.0V to 3.6V

Output Current in I_{OH}/I_{OL}

 $V_{CC} = 3.0V \text{ to } 3.6V$ ±24 mA

 $V_{CC} = 2.3V \text{ to } 2.7V$ ±18 mA $V_{CC} = 1.65V \text{ to } 2.3V$ ±6 mA $V_{CC} = 1.4V \text{ to } 1.6V$ ±2 mA

 $V_{CC} = 1.2V$ ±100 mA

Free Air Operating Temperature (T_A) Minimum Input Edge Rate ($\Delta t/\Delta V$)

 V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V 10 ns/V

-40°C to +85°C

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical . Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: IO Absolute Maximum Rating must be observed.

Note 6: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics

| Symbol | Parameter | Conditions | V _{CC} (V) | Min | Max | Units |
|-----------------|---------------------------|---------------------------|------------------------|------------------------|------------------------|-------|
| V _{IH} | HIGH Level Input Voltage | | 2.7 - 3.6 | 2.0 | | |
| | | | 2.3 - 2.7 | 1.6 | | |
| | | | 1.65 - 2.3 | 0.65 × V _{CC} | | V |
| | | | 1.4 - 1.6 | $0.65 \times V_{CC}$ | | |
| | | | 1.2 | $0.65 \times V_{CC}$ | | |
| V _{IL} | LOW Level Input Voltage | | 2.7 - 3.6 | | 0.8 | |
| | | | 2.3 - 2.7 | | 0.7 | |
| | | | 1.65 - 2.3 | | $0.35 \times V_{CC}$ | V |
| | | | 1.4 - 1.6 | | $0.35 \times V_{CC}$ | |
| | | | 1.2 | | 0.15 x V _{CC} | |
| V _{OH} | HIGH Level Output Voltage | I _{OH} = -100 μA | 2.7 - 3.6 | V _{CC} - 0.2 | | |
| | | I _{OH} = -12 mA | 2.7 | 2.2 | | |
| | | I _{OH} = -18 mA | 3.0 | 2.4 | | |
| | | I _{OH} = -24 mA | 3.0 | 2.2 | | |
| | | I _{OH} = -100 μA | 2.3 - 2.7 | V _{CC} - 0.2 | | |
| | | I _{OH} = -6 mA | 2.3 | 2.0 | | |
| | | I _{OH} = -12 mA | 2.3 | 1.8 | | V |
| | | I _{OH} = -18 mA | 2.3 | 1.7 | | |
| | | I _{OH} = -100 μA | 1.65 - 2.3 | V _{CC} - 0.2 | | |
| | | I _{OH} = -6 mA | 1.65 | 1.25 | | |
| | | I _{OH} = -100 μA | 1.4 - 1.6 | V _{CC} - 0.2 | | |
| | | I _{OH} = -2 mA | 1.4 | 1.05 | | |
| | | I _{OH} = -100 μA | 1.2 | V _{CC} - 0.2 | | |

DC Electrical Characteristics (Continued)

| Symbol | Parameter | Conditions | V _{CC} (V) | Min | Max | Units |
|--------------------|---------------------------------------|-----------------------------------------------------------|------------------------|-----|-------|-------|
| V _{OL} | LOW Level Output Voltage | I _{OL} = 100 μA | 2.7 - 3.6 | | 0.2 | |
| | | I _{OL} = 12 mA | 2.7 | | 0.4 | |
| | | I _{OL} = 18 mA | 3.0 | | 0.4 | |
| | | I _{OL} = 24 mA | 3.0 | | 0.55 | |
| | | $I_{OL} = 100 \mu A$ | 2.3 - 2.7 | | 0.2 | |
| | | I _{OL} = 12 mA | 2.3 | | 0.4 | V |
| | | I _{OL} = 18 mA | 2.3 | | 0.6 | V |
| | | $I_{OL} = 100 \mu A$ | 1.65 - 2.3 | | 0.2 | |
| | | I _{OL} = 6 mA | 1.65 | | 0.3 | |
| | | $I_{OL} = 100 \mu A$ | 1.4 - 1.6 | | 0.2 | |
| | | I _{OL} = 2 mA | 1.4 | | 0.35 | |
| | | $I_{OL} = 100 \mu A$ | 1.2 | | 0.05 | |
| I | Input Leakage Current | $0 \leq V_I \leq 3.6V$ | 1.2 - 3.6 | | ±5.0 | μА |
| I _{OZ} | 3-STATE Output Leakage | $0 \le V_O \le 3.6V$ $V_I = V_{IH} \text{ or } V_{IL}$ | 1.2 - 3.6 | | ±10.0 | μА |
| I _{OFF} I | Power-OFF Leakage Current | $0 \le (V_I, V_O) \le 3.6V$ | 0 | | 10.0 | μА |
| I _{CC} | Quiescent Supply Current | V _I = V _{CC} or GND | 1.2 - 3.6 | | 20.0 | Δ. |
| | | $V_{CC} \le (V_I, V_O) \le 3.6V \text{ (Note 7)}$ | 1.2 - 3.6 | | ±20.0 | μА |
| ΔI_{CC} | Increase in I _{CC} per Input | V _{IH} = V _{CC} -0.6V | 2.7 - 3.6 | | 750 | μА |

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

| Symbol | Parameter | Conditions | V _{CC} | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C,$ | | Units | Figure |
|-------------------------------------|----------------------------------|-----------------------------------------|-----------------|------------------------------------------------|------|-------|--------------------|
| Cynnoon | | Conditions | (V) | Min | Max | 00 | Number |
| t _{PHL} , t _{PLH} | Propagation Delay | $C_L = 30 \text{ pF, } R_L = 500\Omega$ | 3.3 ± 0.3 | 0.8 | 3.0 | | |
| | LE to O _n | | 2.5 ± 0.2 | 1.0 | 3.9 | ns | Figures 1, 2 |
| | | | 1.8 ± 0.15 | 1.5 | 7.8 | | 1,2 |
| | | $C_L = 15 \text{ pF}, R_L = 2k\Omega$ | 1.5 ± 0.1 | 1.0 | 15.6 | ns | Figures |
| | | | 1.2 | 1.5 | 39.0 | 115 | 7, 8 |
| t _{PHL} , t _{PLH} | Propagation Delay | $C_L = 30 \text{ pF}, R_L = 500\Omega$ | 3.3 ± 0.3 | 0.8 | 3.0 | | |
| | I _n to O _n | | 2.5 ± 0.2 | 1.0 | 3.4 | ns | Figures 1, 2 |
| | | | 1.8 ± 0.15 | 1.5 | 6.8 | | .,_ |
| | | $C_L = 15 \text{ pF}, R_L = 2k\Omega$ | 1.5 ± 0.1 | 1.0 | 13.6 | ns | Figures |
| | | | 1.2 | 1.5 | 34.0 | 115 | 7, 8 |
| t_{PZL} , t_{PZH} | Output Enable Time | $C_L = 30 \text{ pF}, R_L = 500\Omega$ | 3.3 ± 0.3 | 0.8 | 3.5 | ns | Figures 1, 3, 4 |
| | | | 2.5 ± 0.2 | 1.0 | 4.6 | | |
| | | | 1.8 ± 0.15 | 1.5 | 9.2 | | ., 0, . |
| | | $C_L = 15 \text{ pF}, R_L = 2k\Omega$ | 1.5 ± 0.1 | 1.0 | 18.4 | ns | Figures |
| | | | 1.2 | 1.5 | 46.0 | | 7, 9, 10 |
| t _{PLZ} , t _{PHZ} | Output Disable Time | $C_L = 30 \text{ pF, } R_L = 500\Omega$ | 3.3 ± 0.3 | 0.8 | 3.5 | | 1_ |
| | | | 2.5 ± 0.2 | 1.0 | 3.8 | ns | Figures 1, 3, 4 |
| | | | 1.8 ± 0.15 | 1.5 | 6.8 | | ., 0, . |
| | | $C_L = 15 \text{ pF}, R_L = 2k\Omega$ | 1.5 ± 0.1 | 1.0 | 13.6 | 20 | Figures |
| | | | 1.2 | 1.5 | 34.0 | ns | 7, 9, 10 |
| T _S | Setup Time | $C_L = 30 \text{ pF, } R_L = 500\Omega$ | 3.3 ± 0.3 | 1.5 | | | |
| | | | 2.5 ± 0.2 | 1.5 | | ns | Figures 1, 6 |
| | | | 1.8 ± 0.15 | 2.5 | | 1 | 1, 0 |
| | | $C_L = 15 \text{ pF}, R_L = 2k\Omega$ | 1.5 ± 0.1 | 3.0 | | ns | Figures |
| | | | 1.2 | 6.0 | | 115 | 6, 7 |

AC Electrical Characteristics (Continued)

| Symbol | Parameter | Conditions | V _{CC} | T _A = -40° | C to +85°C, | Units | Figure |
|-------------------|-----------------------|-----------------------------------------|-----------------|-----------------------|-------------|-------|-----------------|
| Cymbol | | Conditions | (V) | Min | Max | | Number |
| T _H | Hold Time | $C_L = 30 \text{ pF}, R_L = 500\Omega$ | 3.3 ± 1.0 | 1.0 | | | |
| | | | 2.5 ± 0.2 | 1.0 | | ns | Figures 1, 6 |
| | | | 1.8 ± 0.15 | 1.0 | | | ., 0 |
| | | $C_L = 15 \text{ pF}, R_L = 2k\Omega$ | 1.5 ± 0.1 | 1.2 | | ns | Figures |
| | | | 1.2 | 3.6 | | | 6, 7 |
| T _W | Pulse Width | $C_L = 30 \text{ pF}, R_L = 500\Omega$ | 3.3 ± 0.3 | 1.5 | | ns | Figures 1, 4 |
| | | | 2.5 ± 0.2 | 1.5 | | | |
| | | | 1.8 ± 0.15 | 4.0 | | | |
| | | $C_L = 15 \text{ pF}, R_L = 2k\Omega$ | 1.5 ± 0.1 | 4.0 | | no | Figures |
| | | | 1.2 | 8.0 | | ns | 4, 7 |
| toshl | Output to Output Skew | $C_L = 30 \text{ pF, } R_L = 500\Omega$ | 3.3 ± 0.3 | | 0.5 | | |
| t _{OSLH} | (Note 9) | | 2.5 ± 0.2 | | 0.5 | | |
| | | | 1.8 ± 0.15 | | 0.75 | ns | |
| | | $C_L = 15 \text{ pF}, R_L = 2k\Omega$ | 1.5 ± 0.1 | | 1.5 | İ | |
| | | | 1.2 | | 1.5 | | |

Note 8: For $C_L = 50_P F$, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

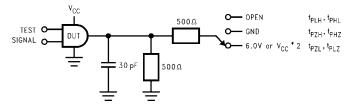
Dynamic Switching Characteristics

| Symbol | Parameter | Conditions | V _{CC} | $T_A = +25^{\circ}C$ | Units |
|------------------|---------------------------------------------|------------------------------------------------------|-----------------|----------------------|-------|
| Cymbol | i didilicio | Conditions | (V) | Typical | Omio |
| V _{OLP} | Quiet Output Dynamic Peak V _{OL} | $C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$ | 1.8 | 0.25 | |
| | | | 2.5 | 0.6 | V |
| | | | 3.3 | 0.8 | |
| V _{OLV} | Quiet Output Dynamic Valley V _{OL} | $C_L = 30 \text{ pF, } V_{IH} = V_{CC}, V_{IL} = 0V$ | 1.8 | -0.25 | _ |
| | | | 2.5 | -0.6 | V |
| | | | 3.3 | -0.8 | |
| V _{OHV} | Quiet Output Dynamic Valley V _{OH} | $C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$ | 1.8 | 1.5 | |
| | | | 2.5 | 1.9 | V |
| | | | 3.3 | 2.2 | |

Capacitance

| Symbol | Parameter | Conditions | T _A = +25°C | Units |
|------------------|-------------------------------|----------------------------------------------------------------------------------------------|------------------------|-------|
| , | | | Typical | • |
| C _{IN} | Input Capacitance | $V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC} | 6.0 | pF |
| C _{OUT} | Output Capacitance | $V_{I} = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$ | 7.0 | pF |
| C _{PD} | Power Dissipation Capacitance | V _I = 0V or V _{CC} , f = 10 MHz, V _{CC} = 1.8V, 2.5V or 3.3V | 20.0 | pF |
| | | V _{CC} = 1.8V, 2.5V or 3.3V | 20.0 | ρı |

AC Loading and Waveforms (V $_{CC}$ 3.3V \pm 0.3V to 1.8V \pm 0.15V)



| TEST | SWITCH |
|-------------------------------------|-----------------------------------------------------|
| t _{PLH} , t _{PHL} | Open |
| t_{PZL}, t_{PLZ} | 6V at $V_{CC} = 3.3 \pm 0.3V$; |
| | V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V |
| t _{PZH} , t _{PHZ} | GND |

FIGURE 1. AC Test Circuit

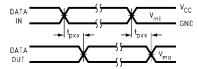


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

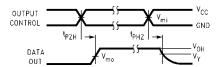


FIGURE 3. 3-STATE Output HIGH Enable and Disable Times for Low Voltage Logic

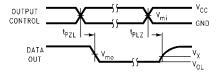


FIGURE 4. 3-STATE Output LOW Enable and Disable Times for Low Voltage Logic

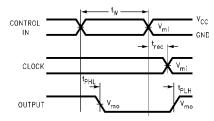


FIGURE 5. Propagation Delay, Pulse Width and $\rm t_{\rm rec}$ Waveforms

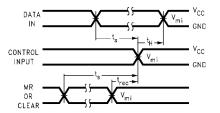
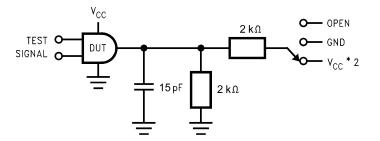


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

| Symbol . | V _{CC} | | |
|-----------------|------------------------|-------------------------|-------------------------|
| | 3.3V ± 0.3V | 2.5V ± 0.2V | 1.8V ± 0.15V |
| V _{mi} | 1.5V | V _{CC} /2 | V _{CC} /2 |
| V _{mo} | 1.5V | V _{CC} /2 | V _{CC} /2 |
| V _X | V _{OL} + 0.3V | V _{OL} + 0.15V | V _{OL} + 0.15V |
| V _Y | V _{OH} – 0.3V | V _{OH} – 0.15V | V _{OH} – 0.15V |

AC Loading and Waveforms (V $_{CC}$ 1.5 \pm 0.1V to 1.2V)



t_{PZH}, t_{PHZ}

| TEST | SWITCH |
|-------------------------------------|-------------------------------------------|
| t _{PLH} , t _{PHL} | Open |
| t_{PZL}, t_{PLZ} | V_{CC} x 2 at V_{CC} = 1.5 \pm 0.1V |
| t_{PZH}, t_{PHZ} | GND |

FIGURE 7. AC Test Circuit

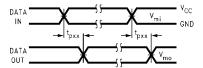


FIGURE 8. Waveform for Inverting and Non-Inverting Functions

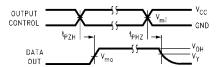


FIGURE 9. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

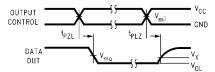
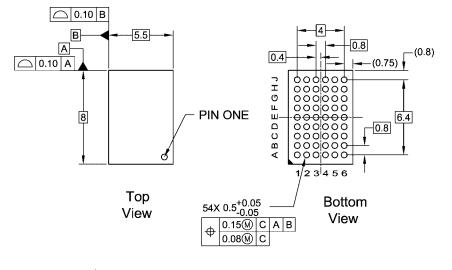
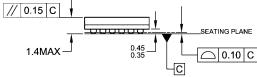


FIGURE 10. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

| Symbol | v _{cc} | |
|-----------------|------------------------|--|
| Cymbol | 1.5V ± 0.1V | |
| V _{mi} | V _{CC} /2 | |
| V _{mo} | V _{CC} /2 | |
| V _X | V _{OL} + 0.1V | |
| V_{Y} | V _{OH} – 0.1V | |

Physical Dimensions inches (millimeters) unless otherwise noted





NOTES:

- A. THIS PACKAGE CONFORMS TO JEDEC M0-205
- **B. ALL DIMENSIONS IN MILLIMETERS**
- C. LAND PATTERN RECOMMENDATION: NSMD (Non Solder Mask Defined)
 .35MM DIA PADS WITH A SOLDERMASK OPENING OF .45MM CONCENTRIC TO PADS
 D. DRAWING CONFORMS TO ASME Y14.5M-1994

BGA54ArevD

54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide Package Number BGA54A (Preliminary)

Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 12.50±0.10 0.40 TYP -B-99. 9.20 8.10 50. O.2 C B A ALL LEAD TIPS PIN #1 IDENT 0.50 LAND PATTERN RECOMMENDATION 0.1 C SEE DETAIL A 0.90+0.15 ALL LEAD TIPS 0.09-0.20 0.10±0.05 0.17-0.27 0.50 ♦ 0.13@ A BS CS 12.00' TOP & BOTTOM DIMENSIONS ARE IN MILLIMETERS R0.16 GAGE PLANE 0.25 NOTES: A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION ED, DATE 4/97. B. DIMENSIONS ARE IN MILLIMETERS. SEATING PLANE 0.60±0.10 1.00 C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS. D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982. DETAIL A MTD48REVC

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD48

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